

## 30V N-Channel Mosfet

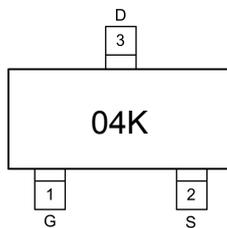
### FEATURES

- $R_{DS(ON)} \leq 0.45\Omega$  (0.35 $\Omega$  Typ.)  
@ $V_{GS}=10V$
- $R_{DS(ON)} \leq 0.52\Omega$  (0.42 $\Omega$  Typ.)  
@ $V_{GS}=4.5V$
- $R_{DS(ON)} \leq 0.80\Omega$  (0.65 $\Omega$  Typ.)  
@ $V_{GS}=2.5V$

### APPLICATIONS

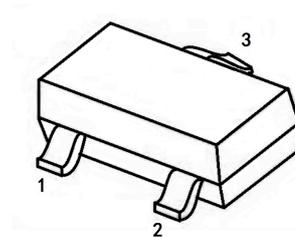
- Relay driver
- High-speed line driver
- Low-side load switch
- Switching circuits

### MARKING



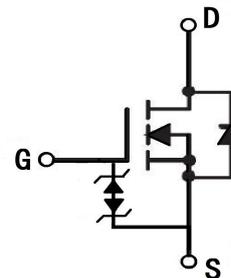
04K : Device Code

### SOT-323



1. GATE
2. SOURCE
3. DRAIN

### N-CHANNEL MOSFET



### MAXIMUM RATINGS (Ta=25°C unless otherwise noted)

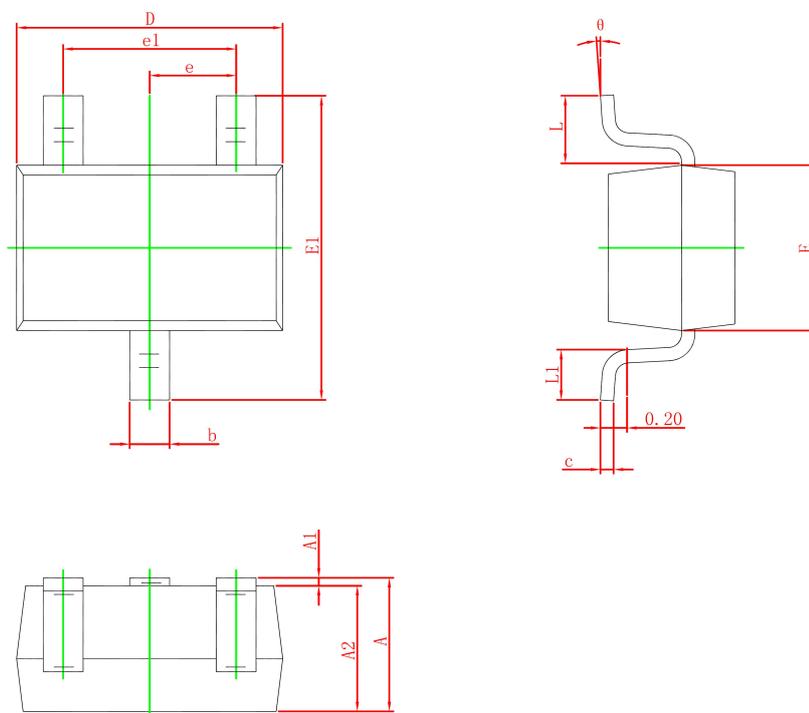
Symbol	Parameter	Max.	Units
$V_{DSS}$	Drain-Source Voltage	30	V
$V_{GSS}$	Gate-Source Voltage	$\pm 12$	V
$I_D$	Continuous Drain Current	0.7	A
$I_{DM}$	Pulsed Drain Current	3	A
$P_D$	Power Dissipation	0.15	W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	833	$^{\circ}C/W$
$T_J$	Junction Temperature	150	$^{\circ}C$
$T_{STG}$	Storage Temperature Range	-55 to +150	$^{\circ}C$

**MOSFET ELECTRICAL CHARACTERISTICS Ta=25 °C unless otherwise specified**

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
<b>Off Characteristic</b>						
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	30	-	-	V
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = 24V,$ $V_{GS} = 0V, T_J = 25^\circ C$	-	-	0.1	$\mu A$
$I_{GSS}$	Gate to Body Leakage Current	$V_{GS} = \pm 12V, V_{DS} = 0V$	-	-	$\pm 10$	$\mu A$
<b>On Characteristics</b>						
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\mu A$	0.6	1	1.3	V
$R_{DS(on)}$	Static Drain-Source On-Resistance	$V_{GS} = 10V, I_D = 0.5A$	-	0.35	0.45	$\Omega$
		$V_{GS} = 4.5V, I_D = 0.4A$	-	0.42	0.52	
		$V_{GS} = 2.5V, I_D = 0.3A$	-	0.65	0.80	
<b>Dynamic Characteristics</b> <small>note1</small>						
$C_{iss}$	Input Capacitance	$V_{DS} = 15V, V_{GS} = 0V,$ $f = 1.0MHz$	-	30.3	-	pF
$C_{oss}$	Output Capacitance		-	5.8	-	pF
$C_{rss}$	Reverse Transfer Capacitance		-	4.2	-	pF
<b>Switching Characteristics</b> <small>note1</small>						
$t_{d(on)}$	Turn-On Delay Time	$V_{GS} = 4.5V, V_{DS} = 15V$ $R_G = 10\Omega, I_D = 0.59A$	-	-	4	ns
$t_r$	Turn-On Rise Time		-	-	7	ns
$t_{d(off)}$	Turn-Off Delay Time		-	-	12	ns
$t_f$	Turn-Off Fall Time		-	-	3	ns
<b>Drain-Source Diode Characteristics and Maximum Ratings</b>						
$V_{SD}$	Drain to Source Diode Forward Voltage	$V_{GS} = 0V, I_S = 0.5A$ $T_J = 25^\circ C$	0.5	-	1.35	V

Notes: 1. Guaranteed by design, not subject to production

## SOT-323 PACKAGE OUTLINE DRAWING



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.200	0.400	0.008	0.016
c	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.650 TYP.		0.026 TYP.	
e1	1.200	1.400	0.047	0.055
L	0.525 REF.		0.021 REF.	
L1	0.260	0.460	0.010	0.018
$\theta$	0°	8°	0°	8°